SINGLE 5.0V, 3.3 TO 3.8 GHZ LINEAR POWER AMPLIFIER

Package Style: QFN, 16-Pin, 3mmx3mmx0.45mm



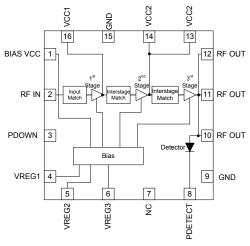


Features

- High Gain; 32dB
- 2.5% EVM (RMS) at 26dBm, 5.0V
- Integrated Power Detector
- High Impedance Enable
- Integrated Input Match
- Footprint compatible to RF5602

Applications

- WiMAX Customer Premises
 Equipment
- WiMAX Access Points
- IEEE 802.16 WiMAX Systems



Functional Block Diagram

Product Description

The RF5623 is a linear power amplifier IC designed specifically for WiMAX medium power applications. The device is manufactured on an advanced InGaP Heterojunction Bipolar Transistor (HBT) process, and has been designed for use as the final RF amplifier in 802.16e transmitters. The device is provided in a 3mmx3mmx0.45mm, 16-pin, leadless chip carrier with a backside ground. The RF5623 is designed to maintain linearity over a wide range of conditions and power outputs.

Optimum Technology Matching® Applied				
☐ GaAs HBT	☐ SiGe BiCMOS	☐ GaAs pHEMT	☐ GaN HEMT	
☐_GaAs MESFET	☐ Si BiCMOS	☐ Si CMOS	☐ RF MEMS	
✓ InGaP HBT	☐ SiGe HBT	☐ Si BJT	LDMOS	



Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage (RF Applied)	-0.5 to +5.25	V
Supply Voltage (No RF Applied)	-0.5 to +6.0	V
DC Supply Current	850	mA
Input RF Power	+10*	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C
Moisture Sensitivity	MSL1	

^{*}Note: Maximum input power with a 50Ω load.



Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

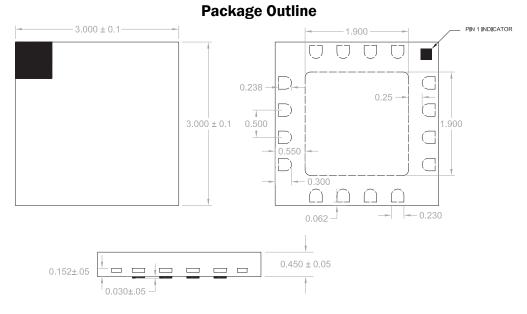
RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

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Parameter	Specification		I linit	Condition	
	Min.	Тур.	Max.	Unit	Condition
Compliance WiMAX IEEE802.16e					Nominal Condition T=25 °C, V _{CC} =5.0V, V _{REG} =2.85V, Freq=Full frequency range and duty cycle=37.029% unless otherwise specified. 802.16e 16QAM modulation with 10MHz BW signal
Frequency Range	3.3		3.6	GHz	
	3.6		3.8	GHz	
Output Power		26		dBm	
EVM		2.5	3.5	%	at P _{OUT} =26dBm
Operating Current		600	700	mA	
Quiescent Current		380	470	mA	V _{CC} =5.0V, V _{REG} =2.85V, RF=Off
I _{REG}			10	mA	
P _{DOWN} Current			10	mA	
Leakage Current			1	mA	V _{CC} =5.0V, V _{REG} =0V, RF=0ff
Gain	28	32		dB	at Rated output Power
Gain Variation over Temperature		2		±dB	-40°C to +85°C
Low Gain Mode (Gain Reduction)		25		dB	at V _{CC} =5.0V, V _{REG} 1 and 3=2.85V, V _{REG} 2 = Low and Temp=25°C (In this mode the gain of the power amplifier drops by TBD typical from its original gain)
Power Detector	10		29	dBm	Useable power detection range
Input Return Loss		-15	-10	dB	
Output P1dB		32		dBm	with CW signal at V _{CC} =5.0V
Turn-On Time		0.5	1.0	us	Output stable to within 90% of final gain
Thermal Data					
Maximum Junction Temperature for long term reliability, Tj Max		150		°C	P _{OUT} =26dBm, V _{CC} =5VDc, V _{REG} =2.85VDc. T _{REF} = 85°C
Thermal Resistance, Θjc		23.7		°C/W	P_{OUT} = 26dBm, V_{CC} =5VDc, V_{REG} = 2.85VDc, Junction to bottom of QFN package. T_{REF} = 85°C
Thermal Resistance, Θj-Ref		29.7		°C/W	P_{OUT} =26dBm, V_{CC} =5VDc, V_{REG} =2.85VDc, Junction to bottom of PCB. T_{REF} = 85 °C
Human Body Model	1000			V	
Charge Device Model	1000			V	



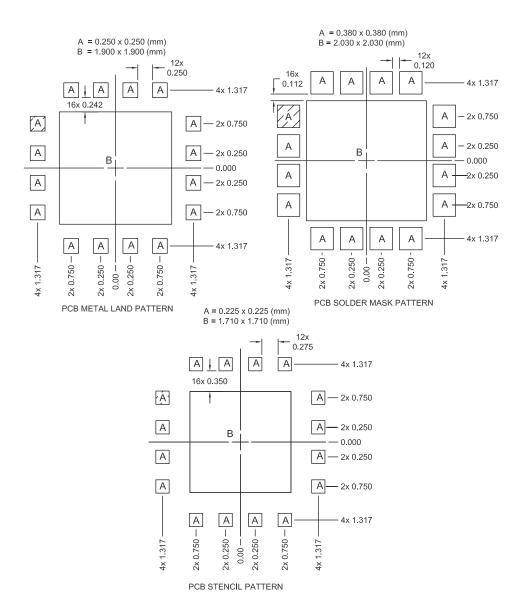
Pin	Function	Description	
1	BIAS VCC	Supply voltage for the bias reference and control circuits. May be connected with VCC1 and VCC2 as long as V_{CC} does not exceed $5.0V_{DC}$ in this configuration.	
2	RF IN	RF input, internally matched and DC block is provided.	
3	PDOWN	Power down pin. Apply $<0.6V_{DC}$ to power down the three power amplifier stages. Apply $1.75V_{DC}$ to $5.0V_{DC}$ to power up. If function is not desired, pin may be connected to V_{REG} .	
7, 9, 15	NC	Not connected. May be connected to ground.	
4	VREG1	First stage input bias voltage. This pin requires a regulated supply to maintain nominal bias current.	
5	VREG2	Second stage input bias voltage. This pin requires a regulated supply to maintain nominal bias current.	
6	VREG3	Third stage input bias voltage. This pin requires a regulated supply to maintain nominal bias current.	
8	P DETECT	Power detector provides an output voltage proportional to the RF output power level.	
10, 11, 12	VCC3/RF OUT	RF output and bias for the output stage. Output is externally matched to 50Ω and needs DC block.	
13, 14	VCC2	Second stage supply voltage.	
16	VCC1	First stage supply voltage.	
Pkg Base	GND	Ground connection. The back side of the package should be connected to the ground plane through as short a connection as possible, e.g., PCB vias under the device are recommended.	



NOTES:

1 Shaded Area is Pin 1 Indicator





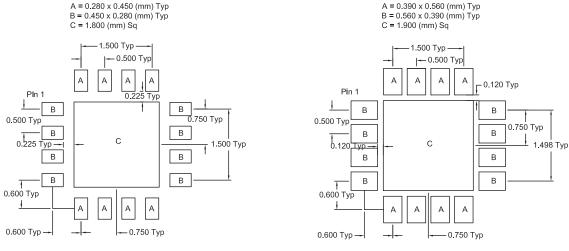
Shaded are represents Pin 1 location.

Note: Thermal vias for center slug "B" should be incorporated into the PCB design. The number and size of thermal vias will depend on the application, the power dissipation, and the electrical requirements. Example of the number and size of vias can be found on the RFMD evaluation board layout.



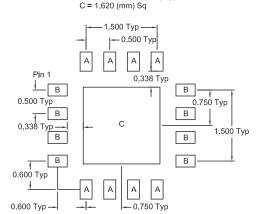
PCB Metal Land and Solder Mask Pattern

Note: If it is desired to build the same PCB to accommodate the RF5602 as well as the RF5623/RF5603 use the following PCB Patterns.



PCB METAL LAND PATTERN

PCB SOLDER MASK PATTERN



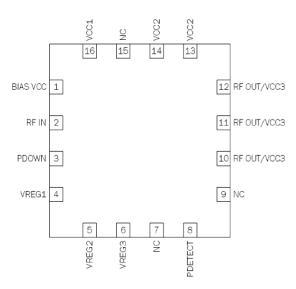
 $A = 0.252 \times 0.405 \text{ (mm) Typ}$ $B = 0.405 \times 0.252 \text{ (mm) Typ}$

PCB STENCIL PATTERN

Note: Thermal vias for center slug "C" should be incorporated into the PCB design. The number and size of thermal vias will depend on the application. Example of the number and size of vias can be found on the RFMD evaluation board layout.

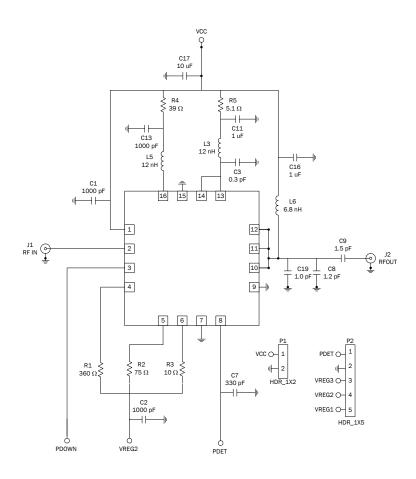


Pin Out



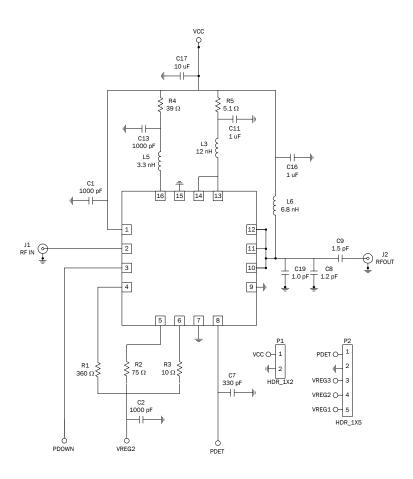


3.3 GHz to 3.6 GHz Schematic



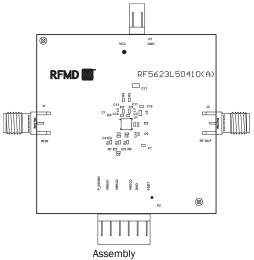


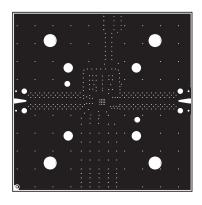
3.6 GHz to 3.8 GHz Schematic

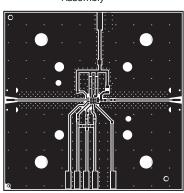


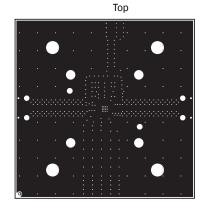


Evaluation Board Layout (RF5623L)

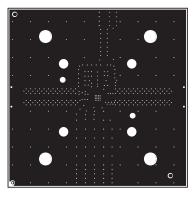








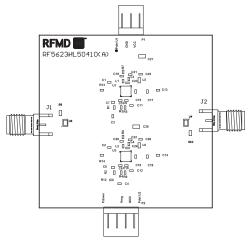
Inner 1 Inner 2

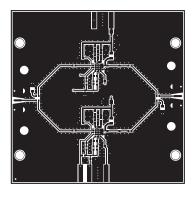


Back

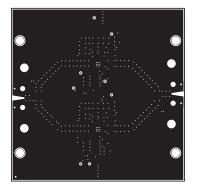


Evaluation Board Layout (RF5623HL)

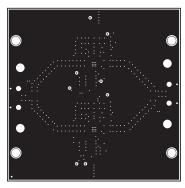




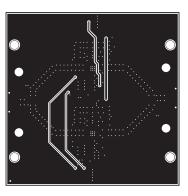
Assembly



Top



Inner 1

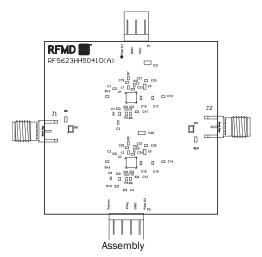


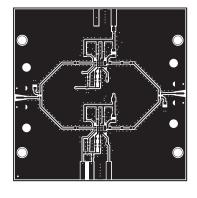
Inner 2

Back

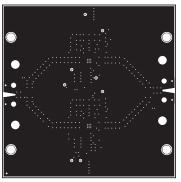


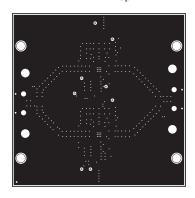
Evaluation Board Layout (RF5623HH)





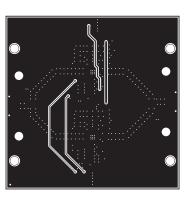
Тор





Inner 2

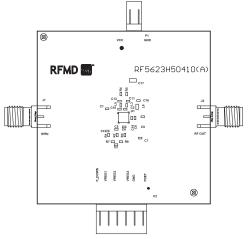
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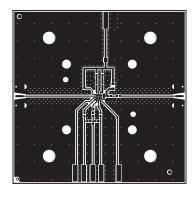


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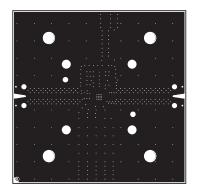


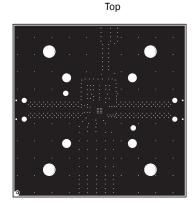
Evaluation Board Layout (RF5623H)





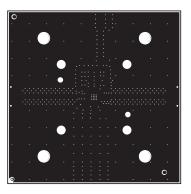
Assembly





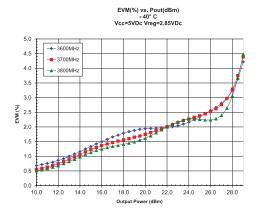
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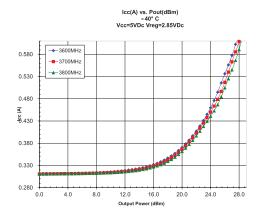
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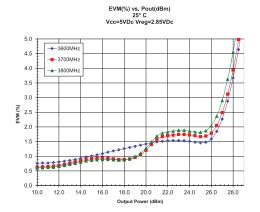


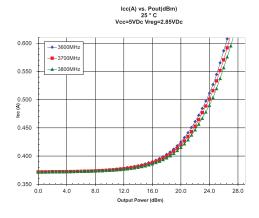
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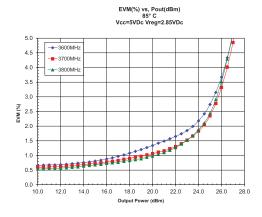


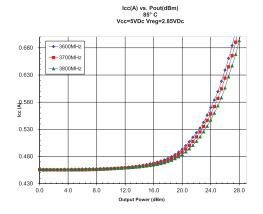




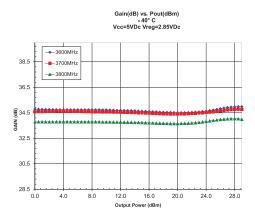


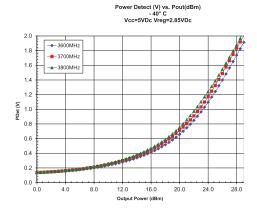


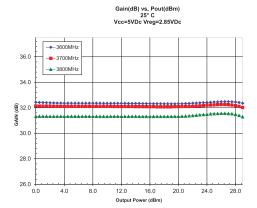


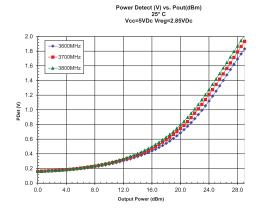


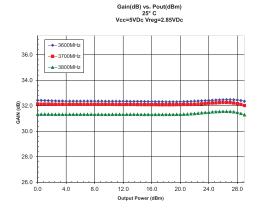


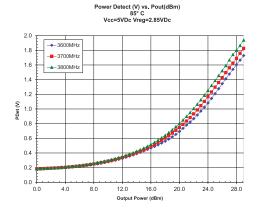






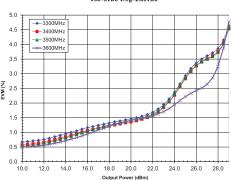




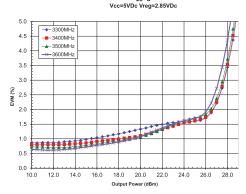




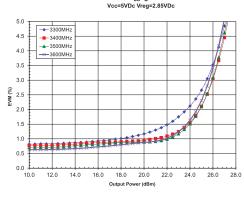




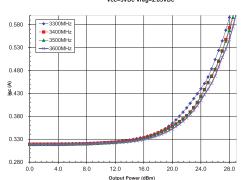
EVM(%) vs. Pout(dBm) 25° C Vcc=5VDc Vreg=2.85VDc



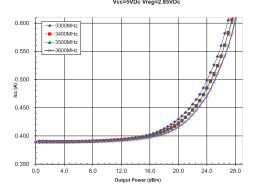
EVM(%) vs. Pout(dBm) 85° C



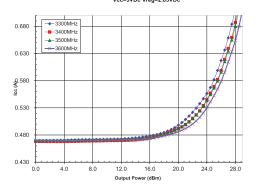
Icc(A) vs. Pout(dBm) - 40° C Vcc=5VDc Vreg=2.85VDc



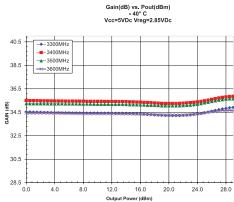
Icc(A) vs. Pout(dBm) 25° C Vcc=5VDc Vreg=2.85VDc

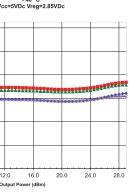


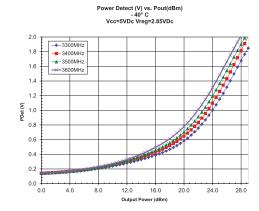
Icc(A) vs. Pout(dBm) 85° C Vcc=5VDc Vreg=2.85VDc

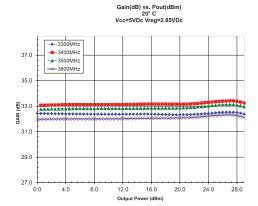


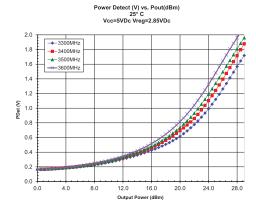


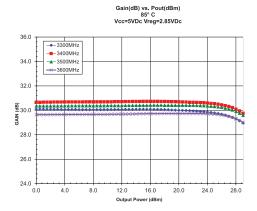


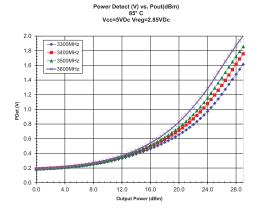














Ordering Information

Ordering Code	Description
RF5623	5.0V, 3.3GHz to 3.8GHz Linear Power Amplifier
RF5623SQ	Standard 25 piece bag
RF5623SR	Standard 100 piece reel
RF5623TR	Standard 2500 piece reel
RF5623L50PCBA-410	3.3 GHz to 3.6 GHz Fully Assembled PCB
RF5623H50PCBA-410	3.6GHz to 3.8GHz Fully Assembled PCB
RF5623HL50PCBA-410	3.3 GHz to 3.6 GHz Balanced Fully Assembled PCB
RF5623HH50PCBA-410	3.6 GHz to 3.8 GHz Balanced Fully Assembled PCB

